

ST13009

High voltage fast-switching NPN power transistor

Features

- Low spread of dynamic parameters
- High voltage capability
- Minimum lot-to-lot spread for reliable operation
- Very high switching speed

Applications

■ Switch mode power supplies

Description

The device is manufactured using high voltage multi-epitaxial planar technology for high switching speeds and medium voltage capability. It uses a Hollow emitter structure to enhance switching speeds.

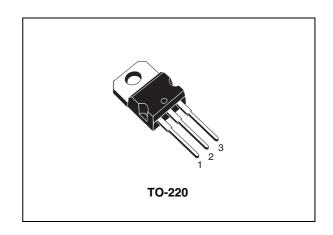


Figure 1. Internal schematic diagram

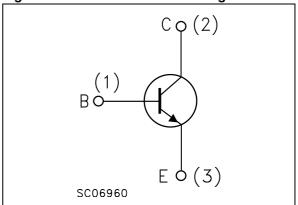


Table 1. Device summary

Order code	Marking ⁽¹⁾	Package	Packaging
ST13009	13009 L 13009 H	TO-220	Tube

^{1.} Product is pre-selected in DC current gain (group L and group H). STMicroelectronics reserves the right to ship either groups according to production availability. Please contact your nearest STMicroelectronics sales office for delivery details.

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ST13009 Electrical ratings

1 Electrical ratings

Table 2. Absolute maximum rating

Symbol	Parameter	Value	Unit
V _{CEV}	Collector-emitter voltage (V _{BE} = -1.5 V)	700	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	400	V
V _{EBO}	Emitter-base voltage (I _C = 0)	12	V
I _C	Collector current	12	Α
I _{CM}	Collector peak current (t _P < 5ms)	24	Α
I _B	Base current	6	Α
I _{BM}	Base peak current (t _P < 5ms)	12	Α
P _{tot}	Total dissipation at T _c = 25°C	100	W
T _{stg}	Storage temperature	-65 to 150	°C
TJ	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{thj-case}	Thermal resistance junction-case Max	1.25	°C/W

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Electrical characteristics ST13009

2 Electrical characteristics

 $(T_{case} = 25^{\circ}C \text{ unless otherwise specified})$

Table 4. Electrical characteristics

Symbol	Parameter	Test Co	Min.	Тур.	Max.	Unit	
I _{CEV}	Collector cut-off current (V _{BE} = -1.5 V)	V _{CE} = 700 V V _{CE} = 700 V	T _C = 100°C			10 500	μ Α μ Α
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = 10 V				10	μА
V _{CEO(sus)} (1)	Collector-emitter sustaining voltage (I _B = 0)	I _C = 10 mA		400			V
		I _C = 4 A	$I_{B} = 0.8 A$			0.85	V
V (1)	Collector-emitter	$I_C = 5 A$	$I_B = 1 A$			0.9	V
V _{CE(sat)} (1)	saturation voltage	I _C = 8 A	$I_{B} = 1.6 A$			1.25	V
		$I_C = 12 A$	$I_B = 3 A$			2.5	V
v (1)	Base-emitter saturation	I _C = 5 A	I _B = 1 A			1.2	V
V _{BE(sat)} (1)	voltage	$I_C = 8 A$	$I_{B} = 1.6 A$			1.6	V
		I _C = 5 A	V _{CE} = 5 V				
h _{FE} (1)(2)	DC current gain	Group L		15		28	
''FE		Group H		26		39	
		$I_C = 8 A$	$V_{CE} = 5 V$	10		30	
	landunativa land	$I_C = 5 A$	$V_{CC} = 250 \text{ V}$				
t _s	Inductive load	I _{B1} = 1 A	$I_{B2} = -2 A$			0.5	
	Storage time	L = 200 μH			1.6	2.5	μs
t _f	Fall time	see Figure 9			60	110	ns
		I _C = 5 A	V _{CC} = 125 V				
t _s	Inductive load Storage time Fall time	$I_{B1} = -I_{B2} = 1$ $L = 200 \mu H$ see <i>Figure 9</i>	.6 A $t_c = 125 ^{\circ}\text{C}$		2.3 110		μs ns

^{1.} Pulsed duration = 300 ms, duty cycle ≤2 %

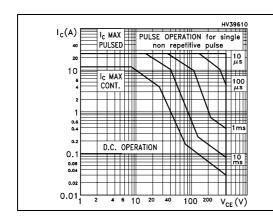
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Product is pre-selected in DC current gain (group L and group H). STMicroelectronics reserves the right to ship either groups according to production availability. Please contact your nearest STMicroelectronics sales office for delivery details.

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

Figure 3. Derating curve



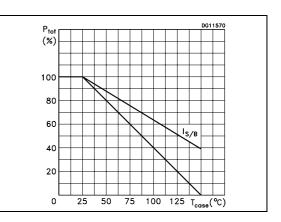
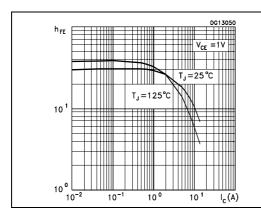


Figure 4. DC current gain

Figure 5. DC current gain



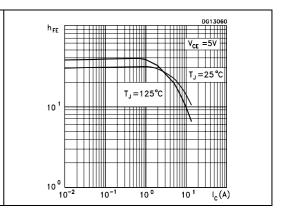
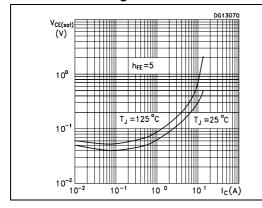
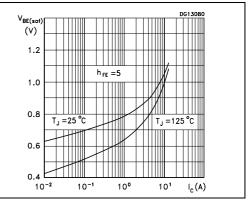


Figure 6. Collector-emitter saturation voltage

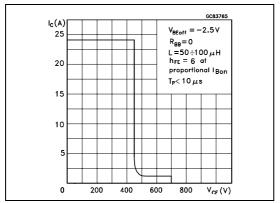
Figure 7. Base-emitter saturation voltage





Electrical characteristics ST13009

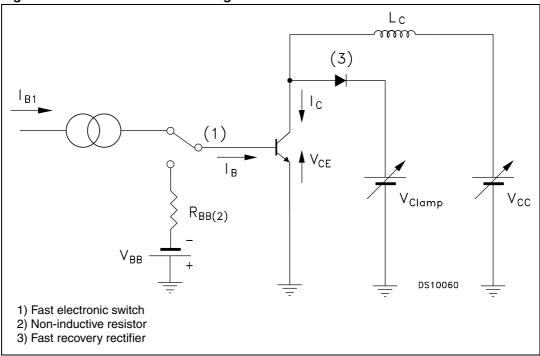
Figure 8. Reverse biased operating area



ST13009 Test circuit

3 Test circuit

Figure 9. Inductive load switching test circuit

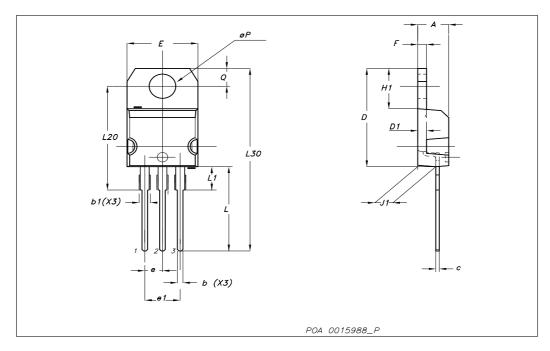


4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

TO-220 mechanical data

Dim		mm			inch		
	Min	Тур	Max	Min	Тур	Max	
Α	4.40		4.60	0.173		0.181	
b	0.61		0.88	0.024		0.034	
b1	1.14		1.70	0.044		0.066	
С	0.49		0.70	0.019		0.027	
D	15.25		15.75	0.6		0.62	
D1		1.27			0.050		
E	10		10.40	0.393		0.409	
е	2.40		2.70	0.094		0.106	
e1	4.95		5.15	0.194		0.202	
F	1.23		1.32	0.048		0.051	
H1	6.20		6.60	0.244		0.256	
J1	2.40		2.72	0.094		0.107	
L	13		14	0.511		0.551	
L1	3.50		3.93	0.137		0.154	
L20		16.40			0.645		
L30		28.90			1.137		
ØP	3.75		3.85	0.147		0.151	
Q	2.65		2.95	0.104		0.116	



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Revision history ST13009

5 Revision history

Table 5. Document revision history

Date	Revision	Changes
12-Jun-2005	1	First version
23-Aug-2007	2	Added figures: 2, and 3

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